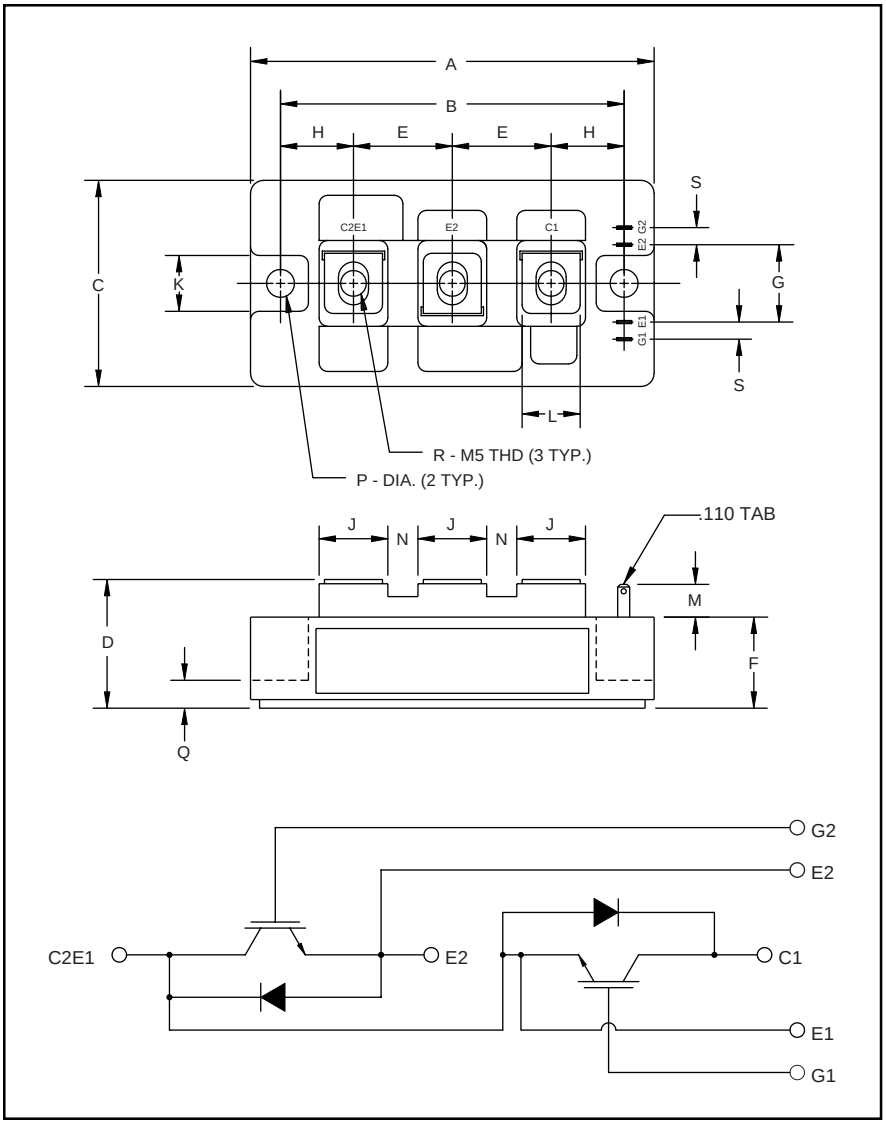
Powerex, Inc., 200 Hillis Street, Youngwood, Pennsylvania 15697-1800 (724) 925-7272

# Dual IGBTMOD™ H-Series Module
## 300 Amperes/600 Volts




**Outline Drawing and Circuit Diagram**

| Dimensions | Inches | Millimeters |
|---|---|---|
| A | 3.70 | 94.0 |
| B | 3.150±0.01 | 80.0±0.25 |
| C | 1.89 | 48.0 |
| D | 1.18 Max. | 30.0 Max. |
| E | 0.90 | 23.0 |
| F | 0.83 | 21.2 |
| G | 0.71 | 18.0 |
| H | 0.67 | 17.0 |
| J | 0.63 | 16.0 |

| Dimensions | Inches | Millimeters |
|---|---|---|
| K | 0.51 | 13.0 |
| L | 0.47 | 12.0 |
| M | 0.30 | 7.5 |
| N | 0.28 | 7.0 |
| P | 0.256 Dia. | Dia. 6.5 |
| Q | 0.26 | 6.5 |
| R | M5 Metric | M5 |
| S | 0.16 | 4.0 |

**Description:**
Powerex IGBTMOD™ Modules are designed for use in switching applications. Each module consists of two IGBT Transistors in a half-bridge configuration with each transistor having a reverse-connected super-fast recovery free-wheel diode. All components and interconnects are isolated from the heat sinking baseplate, offering simplified system assembly and thermal management.

**Features:**
- ☐ Low Drive Power
- ☐ Low $V_{CE(sat)}$
- ☐ Discrete Super-Fast Recovery (70ns) Free-Wheel Diode
- ☐ High Frequency Operation (20-25kHz)
- ☐ Isolated Baseplate for Easy Heat Sinking

**Applications:**
- ☐ AC Motor Control
- ☐ Motion/Servo Control
- ☐ UPS
- ☐ Welding Power Supplies
- ☐ Laser Power Supplies

**Ordering Information:**
Example: Select the complete part module number you desire from the table below -i.e. CM300DY-12H is a 600V ($V_{CES}$), 300 Ampere Dual IGBTMOD™ Power Module.

| Type | Current Rating Amperes | $V_{CES}$ Volts (x 50) |
|---|---|---|
| CM | 300 | 12 |

***CM300DY-12H***
***Dual IGBTMOD™ H-Series Module***
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## Absolute Maximum Ratings, $T_j$ = 25 °C unless otherwise specified

| Ratings | Symbol | CM300DY-12H | Units |
|---|---|---|---|
| Junction Temperature | $T_j$ | –40 to 150 | °C |
| Storage Temperature | $T_{stg}$ | –40 to 125 | °C |
| Collector-Emitter Voltage (G-E SHORT) | $V_{CES}$ | 600 | Volts |
| Gate-Emitter Voltage | $V_{GES}$ | ±20 | Volts |
| Collector Current | $I_C$ | 300 | Amperes |
| Peak Collector Current | $I_{CM}$ | 600* | Amperes |
| Diode Forward Current | $I_F$ | 300 | Amperes |
| Diode Forward Surge Current | $I_{FM}$ | 600* | Amperes |
| Power Dissipation | $P_d$ | 1100 | Watts |
| Max. Mounting Torque M5 Terminal Screws | – | 17 | in-lb |
| Max. Mounting Torque M6 Mounting Screws | – | 26 | in-lb |
| Module Weight (Typical) | – | 270 | Grams |
| V Isolation | $V_{RMS}$ | 2500 | Volts |

* Pulse width and repetition rate should be such that device junction temperature does not exceed the device rating.

## Static Electrical Characteristics, $T_j$ = 25 °C unless otherwise specified

| Characteristics | Symbol | Test Conditions | Min. | Typ. | Max. | Units |
|---|---|---|---|---|---|---|
| Collector-Cutoff Current | $I_{CES}$ | $V_{CE} = V_{CES}$, $V_{GE}$ = 0V | – | – | 1.0 | mA |
| Gate Leakage Current | $I_{GES}$ | $V_{GE} = V_{GES}$, $V_{CE}$ = 0V | – | – | 0.5 | μA |
| Gate-Emitter Threshold Voltage | $V_{GE(th)}$ | $I_C$ = 30mA, $V_{CE}$ = 10V | 4.5 | 6.0 | 7.5 | Volts |
| Collector-Emitter Saturation Voltage | $V_{CE(sat)}$ | $I_C$ = 300A, $V_{GE}$ = 15V | – | 2.1 | 2.8** | Volts |
| | | $I_C$ = 300A, $V_{GE}$ = 15V, $T_j$ = 150°C | – | 2.15 | – | Volts |
| Total Gate Charge | $Q_G$ | $V_{CC}$ = 300V, $I_C$ = 300A, $V_{GS}$ = 15V | – | 900 | – | nC |
| Diode Forward Voltage | $V_{FM}$ | $I_E$ = 300A, $V_{GS}$ = 0V | – | – | 2.8 | Volts |

** Pulse width and repetition rate should be such that device junction temperature rise is negligible.

## Dynamic Electrical Characteristics, $T_j$ = 25 °C unless otherwise specified

| Characteristics | | Symbol | Test Conditions | Min. | Typ. | Max. | Units |
|---|---|---|---|---|---|---|---|
| Input Capacitance | | $C_{ies}$ | $V_{GE}$ = 0V, $V_{CE}$ = 10V, f = 1MHz | – | – | 30 | nF |
| Output Capacitance | | $C_{oes}$ | | – | – | 10.5 | nF |
| Reverse Transfer Capacitance | | $C_{res}$ | | – | – | 6 | nF |
| Resistive | Turn-on Delay Time | $t_{d(on)}$ | $V_{CC}$ = 300V, $I_C$ = 300A, $V_{GE1} = V_{GE2}$ = 15V, $R_G$ = 2.1Ω | – | – | 350 | ns |
| Load | Rise Time | $t_r$ | | – | – | 600 | ns |
| Switching | Turn-off Delay Time | $t_{d(off)}$ | | – | – | 350 | ns |
| Times | Fall Time | $t_f$ | | – | – | 300 | ns |
| Diode Reverse Recovery Time | | $t_{rr}$ | $I_E$ = 300A, $di_E/dt$ = –600A/μs | – | – | 110 | ns |
| Diode Reverse Recovery Charge | | $Q_{rr}$ | $I_E$ = 300A, $di_E/dt$ = –600A/μs | – | 0.81 | – | μC |

## Thermal and Mechanical Characteristics, $T_j$ = 25 °C unless otherwise specified

| Characteristics | Symbol | Test Conditions | Min. | Typ. | Max. | Units |
|---|---|---|---|---|---|---|
| Thermal Resistance, Junction to Case | $R_{th(j-c)}$ | Per IGBT | – | – | 0.11 | °C/W |
| Thermal Resistance, Junction to Case | $R_{th(j-c)}$ | Per FWDi | – | – | 0.24 | °C/W |
| Contact Thermal Resistance | $R_{th(c-f)}$ | Per Module, Thermal Grease Applied | – | – | 0.065 | °C/W |

**CM300DY-12H**
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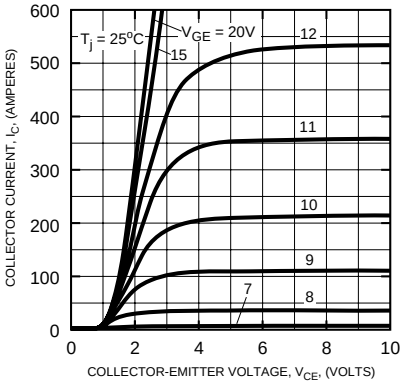
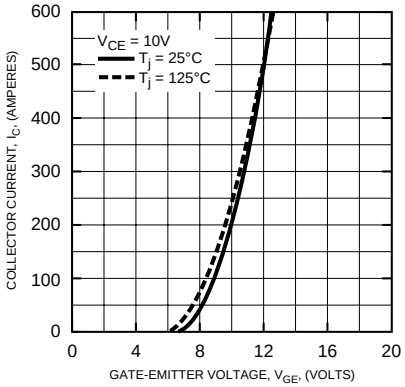
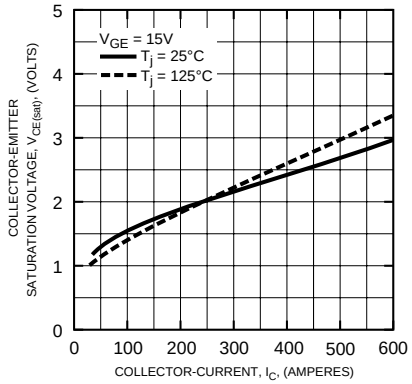
**OUTPUT CHARACTERISTICS (TYPICAL)**




**TRANSFER CHARACTERISTICS (TYPICAL)**




**COLLECTOR-EMITTER SATURATION VOLTAGE CHARACTERISTICS (TYPICAL)**

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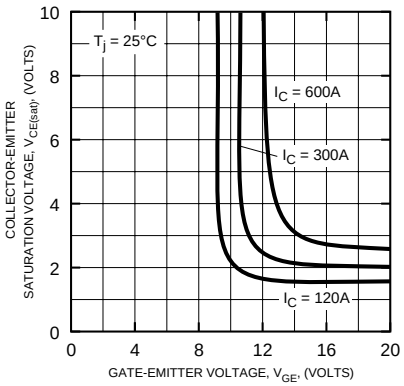
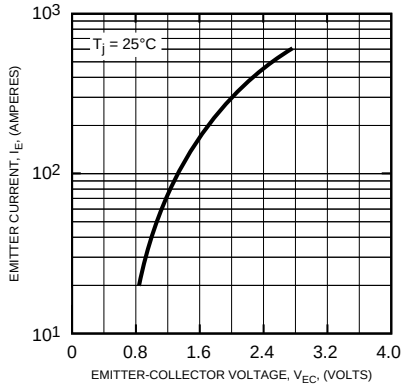
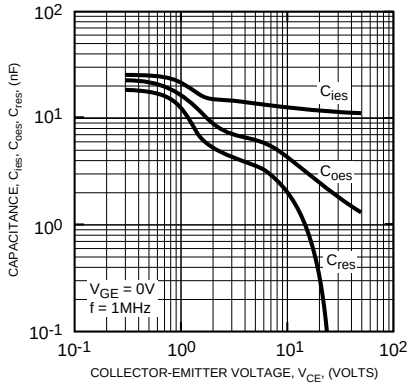


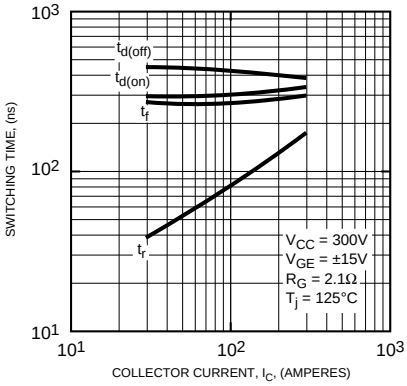

**FREE-WHEEL DIODE FORWARD CHARACTERISTICS (TYPICAL)**



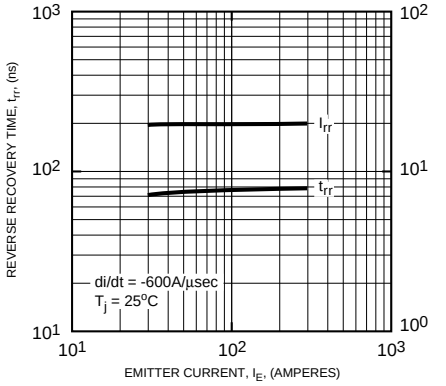

**CAPACITANCE VS. $V_{CE}$ (TYPICAL)**



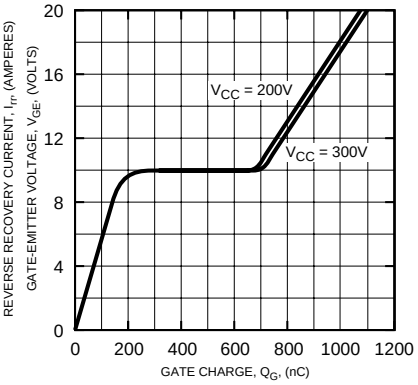

**HALF-BRIDGE SWITCHING CHARACTERISTICS (TYPICAL)**




**REVERSE RECOVERY CHARACTERISTICS (TYPICAL)**




**GATE CHARGE, $V_{GE}$**



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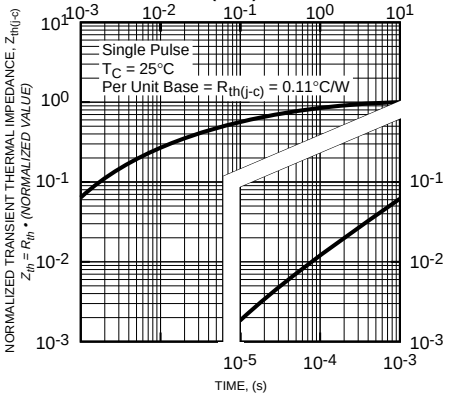
**TRANSIENT THERMAL IMPEDANCE CHARACTERISTICS (IGBT)**




**TRANSIENT THERMAL IMPEDANCE CHARACTERISTICS (FWDi)**